



R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	2.5955	285.3705m	N/A
RT2	15.3264	2.8979	N/A
RT3	11.4405	734.4058m	N/A
RT4	51.2221	596.6741m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	961.2283u	8.0532m	N/A
CT2	14.5446m	5.2671m	N/A
CT3	201.9937m	489.1647u	N/A
CT4	1.2088	7.1523m	N/A

Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	2.9841	596.3746m	N/A
RF2	17.6627	1.3870	N/A
RF3	15.1786	52.5320m	N/A
RF4	44.8720	2.4591	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	1.0740m	316.2890u	N/A
CF2	12.3408m	782.7561u	N/A
CF3	215.8681m	4.4959m	N/A
CF4	1.1907	9.2858u	N/A

Note

- n/a indicates not applicable

